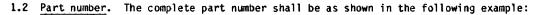
查询"5962-8771401GX"供应商 REVISIONS LTR DATE DESCRIPTION **APPROVED** REV PAGE **REV STATUS REV OF PAGES PAGES** 5 6 8 9 10 11 Marcia B. Kellehor **Defense Electronics** MILITARY DRAWING **Supply Center** This drawing is available for use by Dayton, Ohio all Departments and Agencies of the CHECKED BY Department of Defense TITLE: MICROCIRCUIT, LINEAR, DUAL MATCHED HI-PERFORMANCE OP AMPS, MONOLITHIC Original date of drawing: 15 September SILICON 1987 CODE IDENT. NO. SIZE DWG NO. 5962-87714 67268 AMSC N/A REV PAGE 1 OF 11 5962-E570

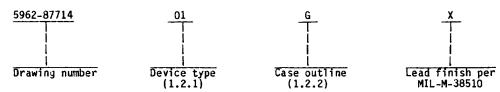
<u>DISTRIBUTION STATEMENT A.</u> Approved for public release; distribution is unlimited. **DESC FORM 193**MAY 86

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1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of  $\overline{\text{MIL}}$ -STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".





1.2.1 Device types. The device types shall identify the circuit function as follows:

Device type	Generic number	Circuit function
01	0P14A	Dual matched high performance operational amplifiers
02	OP 1 4B	Dual matched high performance operational amplifiers

1.2.2 <u>Case outlines</u>. The case outlines shall be as designated in appendix C of MIL-M-38510, and as follows:

Outline letter	Case outline
G	A-1 (8-lead can) TO-5/TO-99, 8
Р	D-4 (8-lead $1/4$ " x $3/8$ "), dual-in-line package $\mathcal{P}$

1.3 Absolute maximum ratings.

Supply voltage	±22 V
Power dissipation $(P_D)$	500 mW
Differential input voltage	±30 V
Input voltage	Supply voltage
Output short-circuit duration	Indefinite
Storage temperature range	-65°C to +150°C
Lead temperature range (soldering, 60 seconds)	+300°C
Junction temperature $(T_1)$	-65°C to +150°C

1.4 Recommended operating conditions.

Supply voltage $(V_{CC})$ Ambient operating temperature										+16 V
Supply voicage (ICC)		-	-	 -	-	_	-	-	-	-10.4
8 mb 2 - 1 - 1 - 1 - 1 - 2 - 2 - 2 - 2 Y - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 -										EE C +- +12E C
Ambient operating temperature	range	-	-	 -	-	-	-	-	-	-55 C tO +125 C

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# "5962-8771401GX"供应商 APPLICABLE DOCUMENTS

2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

**SPECIFICATION** 

MILITARY

MIL-M-38510 - Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883 - Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

- 2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.
  - REQUIREMENTS
- 3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
- 3.2.1 Terminal connections and logic diagrams. The terminal connections and logic diagrams shall be as specified on figure 1.
  - 3.2.2 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.
- 3.3 Electrical performance characteristics. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full recommended ambient operating temperature range.
- 3.4 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.
- 3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.
- 3.6 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.

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	Ţ					1	T		
Test	Symbol     	Conditions -55°C < TA < +125°C unless otherwise specified V <sub>S</sub> = ±15 V				Group A  subgroups   		nits	Uni   
	<u> </u>	<u> </u>	· · · · · · · · · · · · · · · · · · ·	<del></del>			Min	Max	
Input offset voltage	V <sub>OS</sub>	R <sub>S</sub> < 20 I	CΩ	ļ	01	1	-0.75	0.75	mV
		1				2,3	-1.5	(1.5)	
Input offset current	Ios				-	1	-5	5	nA
	ļ			+		2,3	-10	10	
Input bias current	I B	!			-	1	-50	50	nA
	LTVO	1			-	2,3	-60	60	
Input voltage range	I VR	1/			-		±10		<b>V</b>
Common mode rejection	CMRR	V <sub>CM</sub> = IV	) _ +10 V	<u>_</u>	-	2,3	*10 85		dВ
ratio		R <sub>S</sub> < 20	(Ω	į	-	2,3	80		- 40
Power supply rejection	I PSRR	  R <sub>S</sub> < 20	(0		•	1	00	60	uV/
ratio		V <sub>S</sub> = 15	to ±20 V	į	-	2,3		60	,
Output voltage swing	   v <sub>o</sub>	  R <sub>L &gt; 2 ks</sub>	η	<del></del>	-	4	±12		٧
	İ	)   	•	į	-	5,6	±12		•
_arge signal voltage	A <sub>VO</sub>	  R <sub>1</sub> > 2 ks	0 V <sub>0</sub> = ±10 V	Ţ	-	4	100		V/m\
gain	<b>''</b>	 	v	İ	-	5,6	50	Í	•
Power supply current	I <sub>SY</sub>	No load (	each amplifier C		-	1		3 ! 	mA
Power dissipation	IP <sub>D</sub>	No load     T <sub>A</sub> = +25	each amplifier C	1	•	1		90	mW
Channel separation	i Ics	j I	· · · · · · · · · · · · · · · · · · ·	İ	-	7	100		dВ
Output short circuit	I <sub>SC</sub> -				-	1	-60		mA
current	I <sub>SC</sub> +	<u> </u> 				2,3		60	
See footnotes at end of	table.		· · · · · · · · · · · · · · · · · · ·	<u> </u>			<u>.</u> . <u></u>		
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		<del>Ele</del> ctrical performance character	istics -	continued.			
Test	Symbol	Conditions $-55^{\circ}C < T_A < +125^{\circ}C$ $  unless otherwise specified$ $V_S = \pm 15 V$	Device type	Group A	]	ii ts	_ Unit  - 
Input resistance differential mode	IR <sub>IN</sub>	<u>2</u> /	01		Min 2.0	Max	MΩ
Rise time	t <sub>r</sub>	$ A_{VCL}  = +1$ , $V_{IN} = 50 \text{ mV}$ $ R_L  \ge 2 \text{ k}\Omega$ , $ R_S  = 50\Omega$ , $ C_L  = 50 \text{ pF}$	T     	9	1	350	ns
vershoot	os I	$ A_{VCL}  = +1, V_{IN} = 50 \text{ mV}$ $ R_L  \ge 2 \text{ k}\Omega, R_S = 50\Omega,$ $ C_L  = 50 \text{ pF}$		9		10	% 
ilew rate	  SR 	$ R_{L} \ge 2 \text{ k}\Omega, R_{S} = 50 \text{ k}\Omega$ $ C_{L} = 100 \text{ pF}$	†     	7     7   	0.25		<b>V</b> /μ
andwidth	  BW 	Aycl = +1 3/	Ť I I	7	1		MHz
arge signal bandwidth	LSBW	$ V_0 = 20 V_{p-p} \frac{4}{}$		7	4		kHz
nput offset voltage match	Delta VOS		T	2,3	-1 -1.5	1 1.5	mV
ommon mode rejection ratio match	Delta   CMRR	V <sub>CM</sub> = ±10 V, R <sub>S</sub> ≤ 100Ω	† !	1 1	94		dB
TAGEO MAGCII	CPIKK			2,3	90		İ

See footnotes at end of table.

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Test	Symbol	     -55   unless	Conditions C < TA < +125°C otherwise specified V <sub>S</sub> = ±15 V	Device   type	  Group A  subgroups	Limits		Unit
	i I		V <sub>S</sub> = ±15 V	j 	<u> </u> 	   Min	Max	<u> </u>
input offset voltage	v <sub>os</sub>	R <sub>S</sub> < 20 k	Ω	02	1	-5	5	i ∐m∨
		1		<u> </u>	2,3	   -6	(6)	<u> </u>
Input offset current	Ios			!	1	-25	25	l l nA
	 			<u> </u>	2,3	-50	50	) 
Input bias current	I <sub>B</sub>				1	  -100	100	l l nA
	<u> </u>			<u> </u>	2,3	-200	200	<u> </u>
Input voltage range	I I VR	1/		-	1	±10	<u> </u>	ļ v
				+	2,3	±10	<u> </u>	<u> </u>
Common mode rejection	CMRR	V <sub>CM</sub> = IVE	R = ±10 V		1 1	70	<u> </u>	dB
ratio		RS < 20 k		<del> </del>	2,3	70	<u> </u>	<u> </u>
Power supply rejection	PSRR	R <sub>S</sub> ≤ 20 k	Ω / to ±20 ¥		1 1	ļ	150	<u> </u> uV/V
ratio		\\\ \\ \\ \\\\\\\\\\\\\\\\\\\\\\\\\\\\	7 to =20 V	<u> </u>	2,3	<u> </u>	150	
Output voltage swing	v <sub>o</sub>	RL > 2 ks	3		4	±12	<u> </u>	į v
	<u> </u>	<u> </u>		<u> </u>	5,6	±10	<u> </u>	<u> </u>
Large signal voltage	A <sub>VO</sub>	RL > 2 ks	$0  V_0 = \pm 10  V$		4	50	ļ	<b>i V</b> /mV T
gain		<u> </u>		<u> </u>	5,6	25	<u> </u>	<u>i</u>
Power supply current	ISY	No load e	each amplifier C	 	1	<u> </u> 	3	l mA
Power dissipation	IPD	  No load e  T <sub>A</sub> = +25	each amplifier C	T	1		   90 	l mW
Channel separation	ICS			<u> </u>	7	80		l dB
Output short circuit	1 <sub>SC</sub> -				1 1	-60	<del> </del>	] mA
current	I <sub>SC</sub> +	<del> </del> 		   	2,3		60	     
See footnotes at end of	table.	NG	SIZE CODE IDEN		DWG NO.	07714	00	
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Test	Symbol	Conditions   -55°C < TA < +125°C   unless otherwise specified	Device type	Group A    subgroupsT	Lin	   Unit	
		unless otherwise specified   V <sub>S</sub> = ±15 V	cype	Subgroups	Min }	Max	     
Input resistance differential mode	  R <sub>IN</sub>	<u>2/</u>	02	1 1	1.0		<b>Μ</b> Ω
Rise time	  t <sub>r</sub> 	$A_{VCL} = +1$ , $V_{IN} = 50 \text{ mV}$   $R_L \ge 2 \text{ k}\Omega$ , $R_S = 50\Omega$ ,   $C_L = 50 \text{ pF}$		9		350	ns
Overshoot	   0S     	$ A_{VCL}  = +1, V_{IN} = 50 \text{ mV}$ $ R_{L}  \ge 2 \text{ k}\Omega, R_{S} = 50\Omega,$ $ C_{L}  = 50 \text{ pF}$	†     	9     9   		10	%   %
Slew rate	I SR	$ R_L  \ge 2 k\Omega$ , $R_S = 50 k\Omega$ $ C_L  = 100 pF$	†     	7	0.25		   <b>V</b> /μs
Bandwidth	  BW	A <sub>VCL</sub> = +1 <u>3</u> /	†	7	1		MHz
Large signal bandwidth	  LSBW 	V <sub>0</sub> = 20 V <sub>p</sub> - p	<u> </u>	7	4		   kHz 
Input offset voltage match	  Delta   V <sub>OS</sub>		T 	1 1	-1	1	mV
Common mode rejection	    Delta	 	1	2,3	-1.5 94	1.5	 
ratio match	CMRR	$V_{CM} = \pm 10 \text{ V, } R_{S} \leq 100\Omega$		1 1 1	90		l dB

 $<sup>\</sup>underline{1}$ / IVR is guaranteed by CMRR test.

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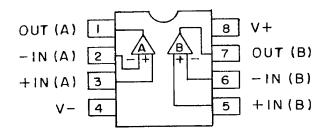
 $<sup>2/</sup>R_{IN}$  is guaranteed by  $I_B$  test.  $R_{IN} = 4KT/qI_B$  where KT/q = .026 V at +25°C.

<sup>3/</sup> Bandwidth is guaranteed by  $t_r$  test. BW = .35/ $t_r$ .

 $<sup>\</sup>underline{4}$ / Large signal bandwidth is guaranteed by SR test. LSBW = SR/2/( $V_{peak}$ ).

## Device types 01 and 02

Case P



Case G

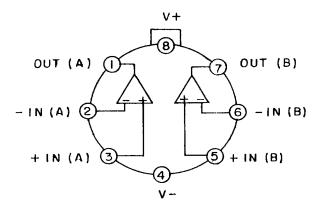
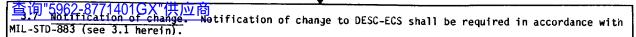


FIGURE 1. Terminal connections and logic diagrams.

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- 3.8 Verification and review. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
  - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
  - a. Burn-in test (method 1015 of MIL-STD-883).
    - Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
    - (2)  $T_A = +125^{\circ}C$ , minimum.
  - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method  $\frac{5005}{5005}$  of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
  - 4.3.1 Group A inspection.
    - a. Tests shall be as specified in table II herein.
    - b. Subgroups 8, 10, and 11 in table I, method 5005 of MIL-STD-883 shall be omitted.
  - 4.3.2 Groups C and D inspections.
    - a. End-point electrical parameters shall be as specified in table II herein.
    - b. Steady-state life test (method 1005 of MIL-STD-883) conditions:
      - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
      - (2)  $T_A = +125$ °C, minimum.
      - (3) Test duration: 1,000 hours, except as permitted by appendix B of MIL-M-38510 and method 1005 of MIL-STD-883.

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## TABLE II. Electrical test requirements.

     MIL-STD-883 test requirements 	Subgroups     (per method     5005, table I)
  Interim electrical parameters   (method 5004)	1
  Final electrical test parameters   (method 5004)	   1*,2,3,4,5,6 
  Group A test requirements   (method 5005)	   1,2,3,4,5,6,
  Groups C and D end-point   electrical parameters   (method 5005)	   1 

<sup>\*</sup>PDA applies to subgroup 1.

### 5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.

#### 6. NOTES

6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.

6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.

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章道 5962-8771401GX 供应商 Approved source of supply is listed herein. Additional sources will be added as they become available. The vendor listed herein has agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

Military drawing part number	Vendor     CAGE     number	Vendor similar part number <u>1</u> /
5962-8771401GX	06665	OP14AZ/883
5962-8771401PX	06665	OP14AJ/883
5962-8771402GX	06665	OP14BZ/883
5962-8771402PX	06665	OP14BJ/883

1/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE number

06665

Vendor name and address

Precision Monolithics, Incorporated 1500 Space Park Drive P.O. Box 58020 Santa Clara, CA 95050

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